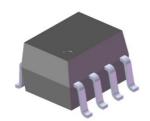


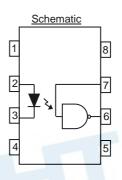
DATASHEET

8 PIN SOP 3.3V HIGH SPEED - 10MBit/s LOGIC GATE PHOTOCOUPLER EL060L



Features

- •Compliance Halogen Free (Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- 3.3 and 5 V dual supply voltage
- High speed 10Mbit/s
- 10kV/µs min. common mode transient immunity
- Guaranteed performance from -40 to 85°C
- Logic gate output, Fan out 10
- High isolation voltage between input and output (Viso=3750 V rms)
- Compliance with EU REACH
- Pb free and RoHS compliant
- UL and cUL approved(No. E214129)
- VDE approved (No. 40028116)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved Description
- CQC approved



A 0.1µF bypass capacitor must be connected between pins 8 and 5 *1

Pin Configuration

- 1, No Connection
- 2, Anode
- 3, Cathode
- 4. No Connection
- 5, Gnd
- 6, Vout
- 7, V_E
- 8, Vcc

Description

The EL060L consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output. It is packaged in a 8-pin SOP package and is suitable for surface mounting technology.

Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface
- High speed logic ground isolation

Truth Table (Positive Logic)

Input	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н
Н	NC	L
L	NC	Н



Absolute Maximum Ratings (T_A=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	50	mA
	Enable input voltage Not exceed V _{CC} by more than 500mV	VE	Vcc + 0.5	V
Input	Enable Input Current	Ι _Ε	5	mA
	Reverse voltage	V_R	5	V
	Power dissipation	P _D	45	mW
	Power dissipation	Pc	85	mW
0	Output current	lo	50	mA
Output Out	Output voltage	Vo	7.0	V
	Supply voltage	V _{CC}	7.0	V
Output P	ower Dissipation	Po	85	mW
Isolation	Isolation voltage *2		3750	V rms
Operating temperature		T _{OPR}	-40 ~ +85	°C
Storage t	Storage temperature		-55 ~ +125	°C
Soldering	g temperature *3	T _{SOL}	260	°C

Notes:

^{*1} The V_{CC} supply must be bypassed by a $0.1\mu F$ capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins

^{*2} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2, 3 & 4 are shorted together, and pins 5, 6, 7 & 8 are shorted together.

^{*3} For 10 seconds



Electrical Characteristics (T_A=-40 to 85°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	VF	-	1.4	1.8	V	I _F = 10mA
Reverse voltage	V _R	5.0	-	-	V	I _R = 10μA
Temperature coefficient of forward voltage	$\Delta V_F / \Delta T_A$	-	-1.8	-	mV/°C	I _F =10mA
Input capacitance	C _{IN}	-	60	-	pF	V _F =0, f=1MHz

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
High level supply current	Іссн	-	5	10	mA	I _F =0mA, V _E =0.5V, V _{CC} =3.3V
Low level supply current	I _{CCL}	-	9	13	mA	I _F =10mA, V _E =0.5V V _{CC} =3.3V
High level enable current	ІЕН		-	-1.6	mA	V _E =2.0 V, V _{CC} =3.3V
Low level enable current	leL	15		-1.6	mA	V _E =0.5 V, V _{CC} =3.3V
High level enable voltage*4	V _{EH}	2.0	-	-	V	I _F =10mA, V _{CC} =3.3V
Low level enable voltage	V _{EL}	-	-	0.8	V	I _F =10mA, V _{CC} =3.3V

Transfer Characteristics (T_A=-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
High level output current	Іон	-	5.0	100	uA	V _{CC} =3.3V, V _O =3.3V, I _F =250µA, V _E =2.0V
Low level output voltage	Vol	-	0.35	0.6	V	$V_{CC} = 3.3V$, $I_F=5mA$, $V_E=2.0V$, $I_{OL}=13mA$
Input threshold current	I _{FT}	-	3	5	mA	V_{CC} = 3.3V, V_{O} =0.6V, V_{E} =2.0V, I_{OL} =13mA

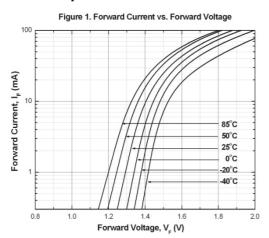


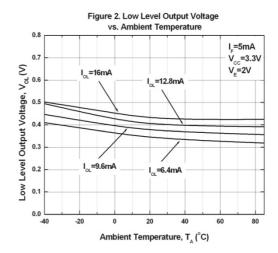
Switching Characteristics (T_A=-40 to 85°C, V_{CC}=3.3V, I_F=7.5mA unless specified otherwise)

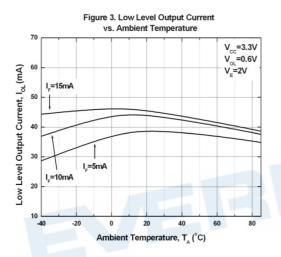
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Propagation delay time to output high level*5 (Fig.12)	t _{PHL}	-	50	75	ns	C _L = 15pF, R _L =350Ω, T _A =25°C
Propagation delay time to output low level*6 (Fig.12)	t _{PLH}	-	45	75	ns	C_L = 15pF, R_L =350 Ω , T_A =25°C
Pulse width distortion	tphl — tplh	-	5	35	ns	$C_L = 15pF, R_L = 350\Omega$
Output rise time* ⁷ (Fig.12)	t _r	-	50	-	ns	$C_L = 15pF, R_L = 350\Omega$
Output fall time*8 (Fig.12)	t _f	-	10	-	ns	$C_L = 15pF, R_L = 350\Omega$
Enable propagation delay time to output High Level*9 (Fig.13)	t _{ELH}	-	30	-	ns	$I_{\text{F}} = 7.5 \text{mA} \; , \; V_{\text{EH}} = 3.0 \text{V}, \\ C_{\text{L}} = 15 \text{pF}, \; R_{\text{L}} = 350 \Omega$
Enable propagation delay time to output low level*10 (Fig.13)	tehl	-	15	-	ns	$I_{\text{F}} = 7.5 \text{mA} \; , \; V_{\text{EH}} = 3.0 \text{V}, \\ C_{\text{L}} = 15 \text{pF}, \; R_{\text{L}} = 350 \Omega$
Common mode transient Immunity at logic high*11	CM _H	10,000		C	V/µS	$\begin{split} &\text{I}_{\text{F}} = 7.5 \text{mA} \;, \; \text{V}_{\text{OH}} = 2.0 \text{V}, \\ &\text{R}_{\text{L}} = 350 \Omega, \; \text{T}_{\text{A}} = 25 ^{\circ} \text{C} \\ &\text{V}_{\text{CM}} = 400 \text{Vp-p} \; (\text{Fig.14}) \end{split}$
Common mode transient immunity at logic low*12	CML	10,000	-	-	V/µS	$\begin{split} I_F &= 0 mA \text{ , } V_{OL} = 0.8 V, \\ R_L &= 350 \Omega, T_A = 25 ^{\circ} C \\ V_{CM} &= 400 Vp\text{-p (Fig.14)} \end{split}$

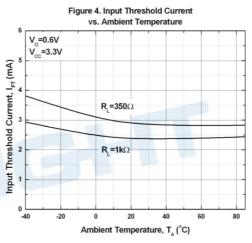


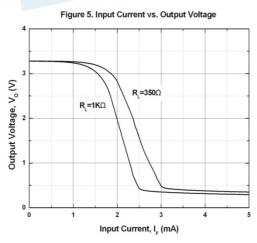
Typical Electro-Optical Characteristics Curves

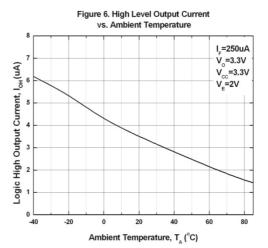


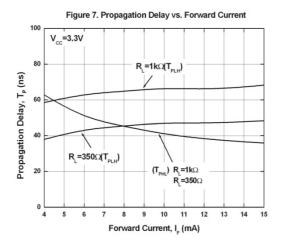


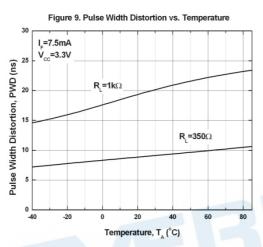


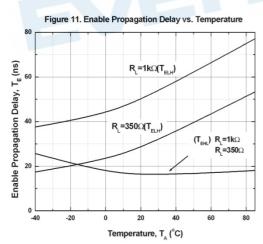


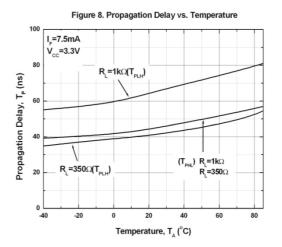












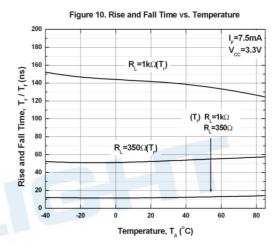


Fig. 12 Test circuit and waveforms for t_{PHL} , t_{PLH} , t_r , and t_f

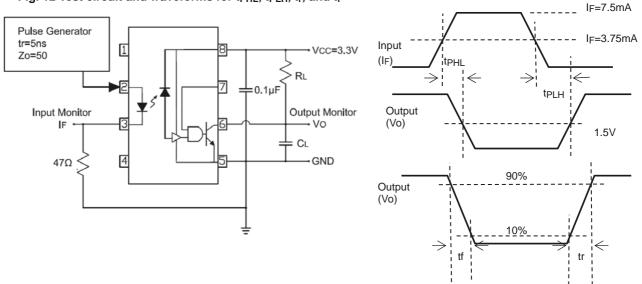


Fig. 13 Test circuit and waveform for tehland telh

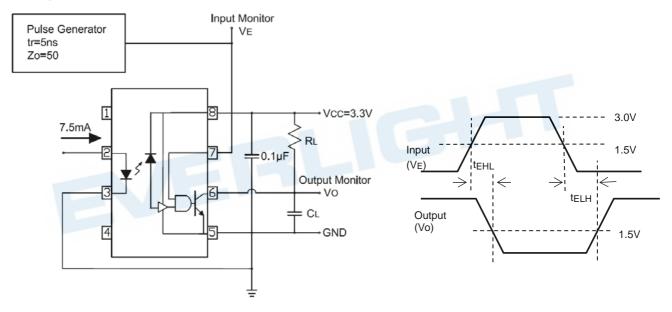
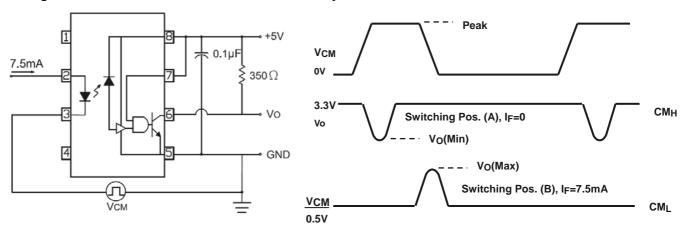


Fig. 14 Test circuit Common mode Transient Immunity





Note

- *4. Enable Input No pull up resistor required as the device has an internal pull up resistor.
- *5. tplh Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- *6. tphl Propagation delay is measured from the 3.75mÅ level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- * 7. t_{r} Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- *8. tf Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- *9. t_{ELH} Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- *10. t_{EHL} Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
- *11 CM_H- The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e., V_{OUT} > 2.0V).
- *12 CM_L— The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e., Vout < 0.8V).

Order Information

Part Number

EL060L(Z)-V

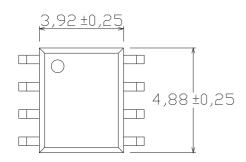
Note

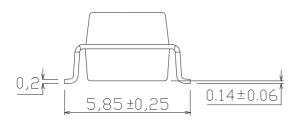
- Z = Tape and reel option (TA, TB or none).
- V = VDE (optional)

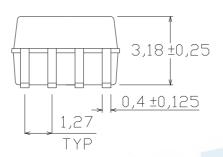
Option	Description	Packing quantity		
None	Standard	100 units per tube		
-V	Standard + VDE	100 units per tube		
(TA)	TA tape & reel option	2000 units per reel		
(TB)	TB tape & reel option	2000 units per reel		
(TA)-V	TA tape & reel option + VDE	2000 units per reel		
(TB)-V	TB tape & reel option + VDE	2000 units per reel		



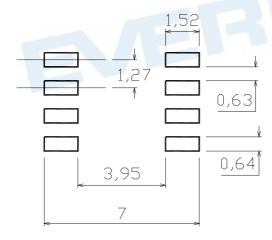
Package Dimension (Dimensions in mm)





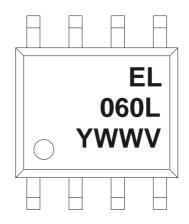


Recommended pad layout for surface mount leadform





Device Marking



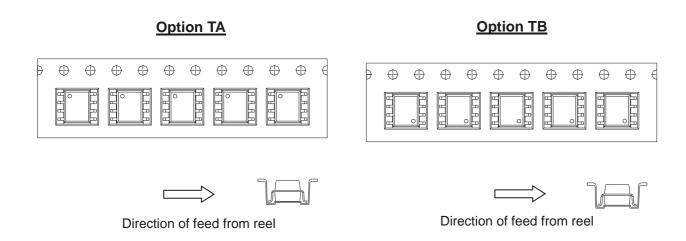
Notes

EL denotes EVERLIGHT
060L denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)

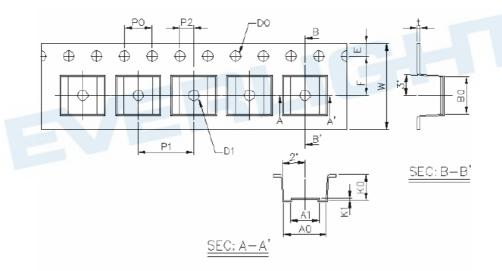




Tape & Reel Packing Specifications



Tape dimension



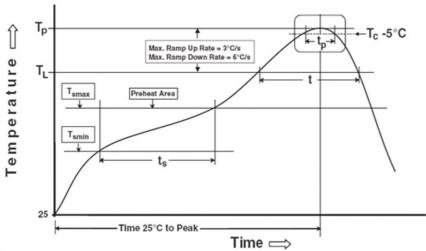
Dimension No.	Α0	A1	В0	D0	D1	E	F
Dimension(mm)	6.2±0.1	4.1±0.1	5.28±0.1	1.5±0.1	1.5±0.3	1.75±0.1	5.5±0.1
Dimension No.	Ро	P1	P2	t	W	K0	K1
Dimension(mm)	4.0±0.1	8.0±0.1	2.0±0.1	0.4±0.1	12.0+0.3/ -0.1	3.7±0.1	0.3±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin}) 150 °C Temperature max (T_{smax}) 200 °C

Time (T_{smin} to T_{smax}) (t_s)

60-120 seconds

Average ramp-up rate (T_{smax} to T_p)

3 °C/second max

Other

Liquidus Temperature (T_L)

Time above Liquidus Temperature (t L)

Peak Temperature (T_P)

Time within 5 °C of Actual Peak Temperature: T_P - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times



Disclaimer

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